

	<h2 style="color: red;">SI7842DP-T1-GE3</h2>
 <p>Image may be representation. See specs for product details.</p>	<b>Hersteller-Teilenummer:</b> <a href="#">SI7842DP-T1-GE3</a>
	<b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a>
	<b>Teil der Beschreibung:</b> MOSFET 2N-CH 30V 6.3A PPAK SO-8
	<b>Datenblätter:</b>  <a href="#">SI7842DP-T1-GE3.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 3812 pcs Stock Available.
	<b>Liefern von:</b> Hong Kong
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	

### Spezifikationen

Teilenummer	<a href="#">SI7842DP-T1-GE3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET 2N-CH 30V 6.3A PPAK SO-8
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	3812 pcs Stock
Serie	LITTLE FOOT®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.4W
Verpackung / Gehäuse	PowerPAK® SO-8 Dual
Supplier Device-Gehäuse	PowerPAK® SO-8 Dual
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6.3A
Rds On (Max) @ Id, Vgs	22 mOhm @ 7.5A, 10V
VGS (th) (Max) @ Id	2.4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI7842DP-T1-GE3 ist neu im Original, Suche SI7842DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7842DP-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7842DP-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>SI7844DP-T1</b> VISHAY SI7844DP-T1 VISHAY	 <b>SI7842DP-T1-E3</b> Vishay / Siliconix MOSFET 2N-CH 30V 6.3A PPAK SO-8	 <b>SI7844DP</b> VISHAY SI7844DP VISHAY	 <b>SI7844DP-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 6.4A PPAK SO-8
 <b>SI7842DP-T1</b> VISHAY VISHAY QFN8	 <b>SI7844DP-T1-E3</b> Vishay / Siliconix MOSFET 2N-CH 30V 6.4A PPAK SO-8	 <b>SI7842DP-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 6.3A PPAK SO-8	 <b>SI7840DY-T1</b> VISHAY VISHAY SOP-8

### heiße Teile

Mehr

- |                                                                                                    |                                                                                                      |                                                                                                     |                                                                                                      |                                                                                                        |
|----------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------|
|  SI7810DN-T1-E3   |  SI7812DN-T1-E3   |  SI7812DN-T1-E3  |  SI7812DN-T1-GE3 |  SI7812DN-T1-GE3  |
|  SI7818DN-T1-E3   |  SI7818DN-T1-E3   |  SI7820DN-T1-E3  |  SI7820DN-T1-E3  |  SI7820DN-T1-GE3  |
|  SI7820DN-T1-GE3  |  SI7840BDP        |  SI7840BDP-T1-E3 |  SI7840BDP-T1-E3 |  SI7840BDP-T1-GE3 |
|  SI7840BDP-T1-GE3 |  SI7840DP         |  SI7840DP-T1     |  SI7840DP-T1-E3  |  SI7840DP-T1-GE3  |
|  SI7840DP-T1-GE3  |  SI7842DP         |  SI7842DP-T1-E3  |  SI7842DP-T1-E3  |  SI7842DP-T1-GE3  |
|  SI7844DP         |  SI7844DP-T1      |  SI7844DP-T1-E3  |  SI7844DP-T1-E3  |  SI7844DP-T1-GE3  |
|  SI7844DP-T1-GE3  |  SI7846DP         |  SI7846DP-T1-E3  |  SI7846DP-T1-E3  |  SI7846DP-T1-GE3  |
|  SI7846DP-T1-GE3  |  SI7846DP-TI      |  SI7846SAC       |  SI7848BDP-T1-E3 |  SI7848BDP-T1-E3  |
|  SI7848BDP-T1-GE3 |  SI7848BDP-T1-GE3 |  SI7848DP        |  SI7848DP-T1-E3  |  SI7848DP-T1-E3   |
|  SI7848DP-T1-GE3  |  SI7850DP         |  SI7850DP-T1-E3  |  SI7850DP-T1-E3  |  SI7850DP-T1-GE3  |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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